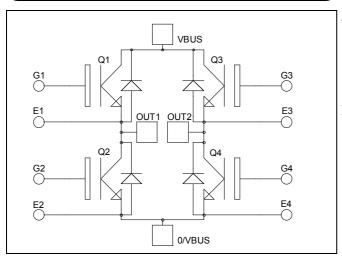


Full - Bridge Fast Trench + Field Stop IGBT3 Power Module



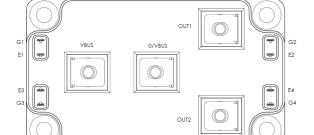


Application

- Welding converters
- Switched Mode Power Supplies
- Uninterruptible Power Supplies
- Motor control

Features

- Fast Trench + Field Stop IGBT3 Technology
 - Low voltage drop
 - Low tail current
 - Switching frequency up to 20 kHz
 - Soft recovery parallel diodes
 - Low diode VF
 - Low leakage current
 - RBSOA and SCSOA rated
- Kelvin emitter for easy drive
 - Very low stray inductance
 - Symmetrical design
 - M5 power connectors
- High level of integration



Benefits

- Stable temperature behavior
- Very rugged
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Easy paralleling due to positive TC of VCEsat
- Low profile
- RoHS Compliant

Absolute maximum ratings

Symbol	Parameter		Max ratings	Unit
V_{CES}	Collector - Emitter Breakdown Voltage		1200	V
I_{C}	Continuous Collector Current	$T_C = 25^{\circ}C$	280	
	Continuous Conector Current	$T_C = 80$ °C	200	A
I_{CM}	Pulsed Collector Current	$T_C = 25$ °C	400	
V_{GE}	Gate – Emitter Voltage		±20	V
P_{D}	Maximum Power Dissipation	$T_C = 25$ °C	890	W
RBSOA	Reverse Bias Safe Operating Area	$T_j = 125$ °C	400A @ 1100V	

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www microsemi com

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All ratings @ $T_j = 25$ °C unless otherwise specified

Electrical Characteristics

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
I_{CES}	Zero Gate Voltage Collector Current	$V_{GE} = 0V, V_{CE} = 1200V$				350	μΑ
V _{CE(sat)}	Collector Emitter Saturation Voltage	$V_{GE} = 15V$	$T_j = 25$ °C	1.4	1.7	2.1	V
		$I_C = 200A \qquad T_j = 125^{\circ}C$	$T_j = 125$ °C		2.0		·
$V_{GE(th)}$	Gate Threshold Voltage	$V_{GE} = V_{CE}$, $I_C = 3 \text{ mA}$		5.0	5.8	6.5	V
I_{GES}	Gate – Emitter Leakage Current	$V_{GE} = 20V, V_{CE} = 0V$				500	nA

Dynamic Characteristics

•	Characteristic	Test Conditions		Min	Тур	Max	Unit
Cies	Input Capacitance	$V_{GE} = 0V$ $V_{CE} = 25V$ $f = 1MHz$			14		nF
C_{oes}	Output Capacitance				0.8		
C_{res}	Reverse Transfer Capacitance				0.6		
$T_{d(on)}$	Turn-on Delay Time	Inductive Switching (25°C) $V_{GE} = \pm 15V$ $V_{Bus} = 600V$ $I_C = 200A$			260		ns
T_{r}	Rise Time				30		
$T_{d(off)}$	Turn-off Delay Time				420		
T_{f}	Fall Time	$R_G = 2.7\Omega$		70			
$T_{d(on)}$	Turn-on Delay Time	Inductive Switching (125°C) $V_{GE} = \pm 15V$ $V_{Bus} = 600V$ $I_{C} = 200A$ $R_{G} = 2.7\Omega$			290		ns
$T_{\rm r}$	Rise Time				50		
$T_{d(off)}$	Turn-off Delay Time				520		
$T_{\rm f}$	Fall Time				90		
Eon	Turn on Energy	$V_{GE} = \pm 15V$ $V_{Bus} = 600V$	$\Gamma_{\rm j} = 125^{\circ}{\rm C}$		20		m I
E _{off}	Turn off Energy	$I_C = 200A$ $R_G = 2.7\Omega$	$\Gamma_{\rm j} = 125^{\circ}{\rm C}$		20		mJ

Reverse diode ratings and characteristics

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
V_{RRM}	Maximum Peak Repetitive Reverse Voltage			1200			V
I_{RM}	Maximum Reverse Leakage Current	V _R =1200V	$T_{i} = 25^{\circ}C$ $T_{i} = 125^{\circ}C$			350 600	μΑ
I_{F}	DC Forward Current		$Tc = 80^{\circ}C$		200		A
V_{F}	Diode Forward Voltage	$I_F = 200A$ $V_{GE} = 0V$	$T_i = 25^{\circ}C$		1.6	2.1	V
v _F			$T_{i} = 125^{\circ}C$		1.6		v
t _{rr}	Reverse Recovery Time	J 200 A	$T_j = 25^{\circ}C$		170		ns
			$T_j = 125$ °C		280		115
0	Q_{rr} Reverse Recovery Charge V_{F}	$\begin{aligned} I_F &= 200A \\ V_R &= 600V \\ di/dt &= 2500A/\mu s \end{aligned}$	$T_j = 25$ °C		18		μС
Q rr			$T_{i} = 125^{\circ}C$		36		μС
Е	E _r Reverse Recovery Energy		$T_j = 25^{\circ}C$		10		m I
\mathbf{E}_{r}		$T_{\rm j} = 125^{\circ}{\rm C}$		18		mJ	

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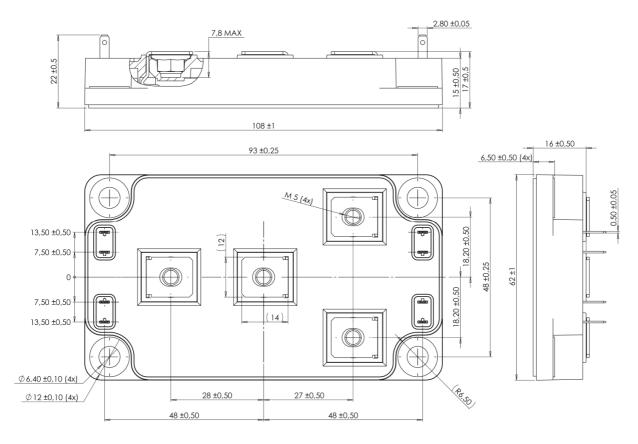
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Thermal and package characteristics

Symbol	Characteristic			Min	Тур	Max	Unit
R_{thJC}	Junction to Case Thermal Resistance		IGBT			0.14	°C/W
			Diode			0.25	
V_{ISOL}	RMS Isolation Voltage, any terminal to case t = 1 min, 50/60Hz			4000			V
T_{J}	Operating junction temperature range			-40		150	°C
T_{STG}	Storage Temperature Range			-40		125	
$T_{\rm C}$	Operating Case Temperature			-40		100	
Torque	Mounting torque	To heatsink	M6	3		5	N.m
		For terminals	M5	2		3.5	11.111
Wt	Package Weight	·				300	g

SP6 Package outline (dimensions in mm)

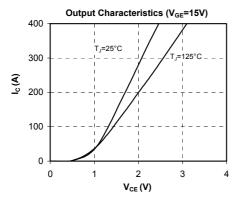


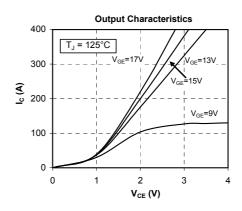
See application note APT0601 - Mounting Instructions for SP6 Power Modules on www.microsemi.com

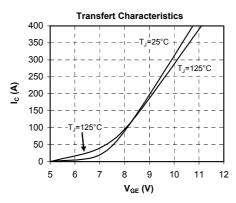
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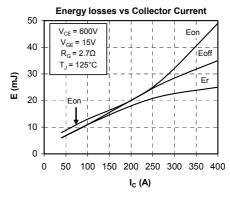


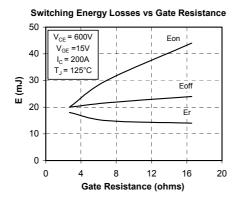
Typical Performance Curve

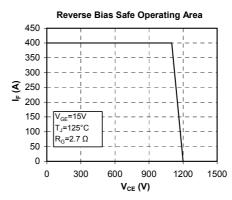


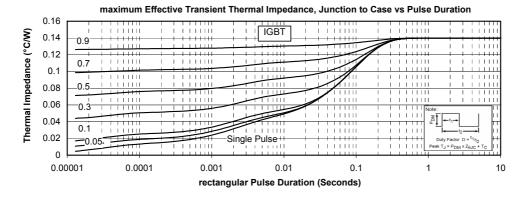






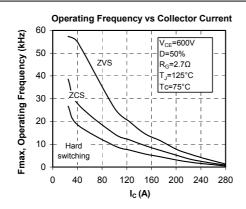


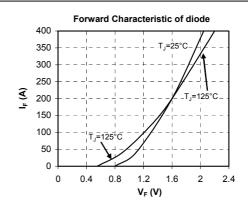


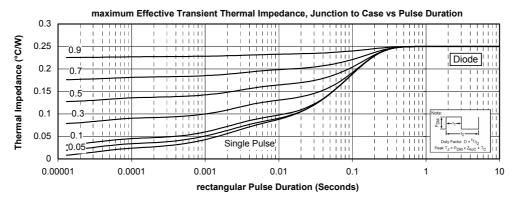


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